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Bis(1,3-dimethyl-1*H*-imidazolium) hexafluorosilicate: the second monoclinic polymorph

Chong Tian, # Wanli Nie # and Maxim V. Borzov*

College of Chemistry, Leshan Normal University, Binhe Rd 778, Leshan 614000, Sichuan Province, People's Republic of China Correspondence e-mail: maxborzov@mail.ru

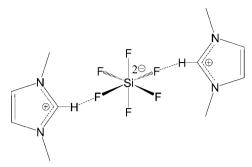
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Key indicators: single-crystal X-ray study; T = 296 K; mean $\sigma(C-C) = 0.002$ Å; R factor = 0.028; wR factor = 0.081; data-to-parameter ratio = 10.2.

The title compound, $2C_5H_9N_2^+\cdot SiF_6^{2-}$, (I), crystallized as a new polymorph, different from the previously reported one (Ia) [Light et al. (2007) private communication (refcode: NIQFAV). CCDC, Cambridge, England]. The symmetry [space groups $P2_1/n$ for (I) and C2/c for(Ia)] and crystal packing patterns are markedly different for this pair of polymorphs. In (I), all imidazolium cations in the lattice are nearly parallel to each other, whereas a herringbone arrangement can be found in (Ia). In (I), each SiF_6^{2-} dianion forms four short $C-H\cdots F$ contacts with adjacent $C_5H_9N_2^+$ cations, resulting in the formation of layers parallel to the ac plane. In (Ia), the $C-H\cdots F$ contacts are generally longer and result in the formation of layers along the bc plane.

Related literature

For the structure of the previously reported polymorph of (I) and its solvatomorph $6C_5H_9N_2^+\cdot 3SiF_6^{2-}\cdot CH_3OH$, see: Light *et al.* (2007) and Tian *et al.* (2013), respectively. For an overview of polymorphism, see: Bernstein (2002); Linden (2011). For the practical importance of sterically non-hindered 1,3-dialkyl-1*H*-imidazolium salts with perfluoro anions of the main-group elements in the preparation of Arduengo carbene adducts, see: Tian *et al.* (2012). For graph-set notation, see: Etter *et al.* (1990); Bernstein *et al.* (1995); Grell *et al.* (1999).



Experimental

Crystal data

•	
$2C_5H_9N^{2+}\cdot SiF_6^{2-}$	$V = 706.53 (12) \text{ Å}^3$
$M_r = 336.38$	Z = 2
Monoclinic, $P2_1/n$	Mo $K\alpha$ radiation
a = 8.2240 (8) Å	$\mu = 0.23 \text{ mm}^{-1}$
b = 9.7901 (9) Å	T = 296 K
c = 8.7753 (9) Å	$0.40 \times 0.39 \times 0.05 \text{ mm}$
$\beta = 90.106 (1)^{\circ}$	

Data collection

 $\begin{array}{ll} \text{Bruker SMART APEXII} & 3670 \text{ measured reflections} \\ \text{diffractometer} & 1373 \text{ independent reflections} \\ \text{Absorption correction: multi-scan} & 1228 \text{ reflections with } I > 2\sigma(I) \\ \text{$(SADABS; Sheldrick, 1996)$} & R_{\text{int}} = 0.020 \\ T_{\text{min}} = 0.913, \ T_{\text{max}} = 0.988 \\ \end{array}$

Refinement

 $\begin{array}{ll} R[F^2 > 2\sigma(F^2)] = 0.028 & 134 \ {\rm parameters} \\ wR(F^2) = 0.081 & {\rm All \ H-atom \ parameters \ refined} \\ S = 1.09 & {\Delta \rho_{\rm max}} = 0.18 \ {\rm e} \ {\rm \mathring{A}}^{-3} \\ 1373 \ {\rm reflections} & {\Delta \rho_{\rm min}} = -0.22 \ {\rm e} \ {\rm \mathring{A}}^{-3} \end{array}$

Table 1 Hydrogen-bond geometry (\mathring{A} , $^{\circ}$).

$D-H\cdots A$	$D-\mathrm{H}$	$H \cdot \cdot \cdot A$	$D \cdot \cdot \cdot A$	$D-H\cdots A$
$C1-H1\cdots F3$ $C2^{i}-H2^{i}\cdots F2$	0.884 (18)	2.164 (19)	2.9622 (17)	149.8 (14)
	0.934 (19)	2.26 (2)	3.1935 (18)	174.0 (5)

Symmetry code: (i) $-x + \frac{1}{2}$, $y + \frac{1}{2}$, $-z + \frac{3}{2}$.

Data collection: *APEX2* (Bruker, 2007); cell refinement: *SAINT* (Bruker, 2007); data reduction: *SAINT*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008) and *OLEX2* (Dolomanov *et al.*, 2009); software used to prepare material for publication: *SHELXTL* and *OLEX2*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: LD2107).

[‡] Previous address: Key Laboratory of Synthetic and Natural Chemistry of the Ministry of Education, College of Chemistry and Material Science, the North-West University of Xi'an, Taibai Bei Avenue 229, Xi'an 710069, Province, People's Republic of China.

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supplementary materials

Acta Cryst. (2013). E69, o1218-o1219 [doi:10.1107/S1600536813018242]

Bis(1,3-dimethyl-1*H*-imidazolium) hexafluorosilicate: the second monoclinic polymorph

Chong Tian, Wanli Nie and Maxim V. Borzov

Comment

Polymorphism of molecular crystals (including pseudopolymorphism and solvatomorphism) is an important object of structural studies [see a monograph (Bernstein, 2002) and an editorial paper (Linden, 2011)]. However, discovery of new polymorphic forms still remains a matter of serendipity.

Recently, being interested in preparation of a variety of sterically non-hindered 1,3-dialkyl-1H-imidazolium salts with main-group element perfluorato anions as potential precursors of Arduengo carbene adducts with the Group 13–15 element fluorides (Tian *et al.*, 2012), we analyzed materials obtained by re-crystallization of crude bis(1,3-dimethyl-1H-imidazolium) hexafluorosilicate, $[C_5H_9N_2^+]_2[SiF_6^2^-]$, from either ethanol or methanol solutions. While crystallization from ethanol afforded only the solvent-free $[C_5H_9N_2^+]_2[SiF_6^2^-]$, (I), the material obtained from methanol presented both (I) (crystals grow on the walls of a vessel above the solution surface during its gradual evaporation into air) and its adduct with methanol, $\{[C_5H_9N_2^+]_2[SiF_6^2^-]\}_3(CH_3OH)$, (II), crystals of which grow at the bottom of a vessel under the layer of the mother liquor. In the latter case, single crystals of (I) and (II) could be easily separated manually. Identity of the single crystals of (I) prepared from EtOH and MeOH was proved by the unit cell measurements. Due to a better quality of the sample of (I) grown from ethanol, only these data are provided and will be referred to further in the discussion.

The β -angle very close to 90° presented a difficulty in determination of the actual crystal system and space group $(P2_1/n)$ for (I). The Si-atoms are positioned on inversion centres. Each $[SiF_6^{2-}]$ moiety forms two pairs of noticeable F···H contacts: F3···H1 and F2···H2ⁱⁱ [symmetry code: (ii) -x + 1/2, y + 1/2, -z + 3/2] and their centrosymmetric equivalents (see Table 1 and Fig. 1). In (I), the plane of the imidazolium ring is nearly perpendicular to the crystallographic [010] plane [interplanar angle 87.25 (4)°] that results in a nearly parallel arrangement of all imidazolium moieties in the lattice (see Fig. 2a). The F···H contacts connect the imidazolium cations and the $[SiF_6^{2-}]$ dianions into layers parallel to the [101] plane (highlightened on Fig. 2a) consisting of the first- and second-order networks $N_1 = D_2^2(4)D_2^2(4)$ and $N_2 = C_2^2(8)$]. Any interlayer C-H···F contacts shorter than 2.5 Å are absent in (I).

The previously reported polymorph (Ia) (Light *et al.*, 2007) has space group C2/c. The principal geometrical parameters of ions in (I) and (Ia) are similar. However, the packing patterns in (I) and (Ia) are distinctly different (compare Figs. 2a and 2 b). Overall, the packing in (Ia) is less dense than that found in (I) [the respective calculated densities D_x are 1.507 Mg m⁻³ for (Ia) at 120 K and 1.581 Mg m⁻³ for (I) at 296 K. In (Ia), the H···F contacts are longer than in (I) and form the first- and second-order networks $N_1=D_2^2(4)D_2^2(4)$ and $N_2=C_2^2(8)$ seemingly similar to those in (I) (primary and secondary contact lengths are equal to 2.334 and 2.359 Å, respectively). This network similarity, however, is only apparent because the secondary H···F contacts in (Ia) are formed not by H⁴, but by a H¹-atom of the Me-group (superscripts here denote the positions in the imidazolium moiety). As recommended previously by Etter *et al.* (1990), the graph set descriptors for (I) and (Ia) could be augmented, respectively, as $N_1=[D_2^2(4)]_{H4}D_2^2(4)$, $N_2=[C_2^2(8)]_{H2,H4}$ and $N_1=[D_2^2(4)]_{H1}D_2^2(4)$,

 $N_2=[C_2^2(8)]_{H2,H1'}$ that allows to exclude any ambiguity.

The longer contacts in (Ia) also form non-interconnected layers in its crystal lattice. The neighbour pairs of layers in (Ia) are connected by the C-centering translation, C_2 rotation, n-glide reflection, and inversion operations. Moreover, these layers belong to the same layer group as it is observed in (I; $p2_1/b11$), with its a' and b' parameters being comparable [9,7901 (9) and 12,0377 (9) Å for (I) and 11,988 and 11,258 Å for (Ia); see Fig. 3; priming is used to distinguish between unit cell axes a and b and layer-related axes a' and b']. Distances between adjacent inversion-related pairs of imidazolium rings are also close (the interplane distances are 3.418 (2) and 3.449 Å in (I) and (Ia), respectively]. Fig. 3 also illustrates that the layers within (I) and (Ia) can be converted one into another by a diffusionless transformation which can be best described as continuous rotations of the inversion-related pairs of imidazolium cations and SiF_6^{2-} groups around the corresponding centers accompanied with dilations/contractions of the layers along the a' and b' directions. Transformation of the entire lattice of (Ia) into that of (I) also requires a mutual (0, 1/2, 0) shear of adjacent layers in the b-direction what results in vanishing of centering translations and conversion of C_2 rotations into 2_1 screw ones. Being a continuous transformation, such a layer shift, however, can not be classified as a "diffusionless" one. Thus, any direct first-order phase transition between (I) and (Ia) is hardly believable. Unfortunately, the lack of the information about the sample crystal of (Ia) [in the corresponding Private communication to the CCDC (Light et al., 2007), no data on the crystallization conditions are provided] does not allow us to outline the actual reasons of the (I)/(Ia) polymorphism. The structure of solvated crystals $\{[C_5H_9N_2^+]_2[SiF_6^{2-}]\}_3(CH_3OH)$, (II) is reported separately (Tian *et al.*, 2013).

Experimental

Crude 1,3-dimethyl-1*H*-imidazolium hexafluorosilicate was prepared by a reaction of 1,3-dimethyl-1*H*-imidazolium iodide and disilver hexafluorosilicate (molar ratio 2:1) in distilled water. Concentration of the filtrate till dryness followed by re-crystallization from ethanol gave (I) in an almost quantitative yield. If methanol is used as a solvent, crystals of both (I) and (II) are formed. Single crystals of (I) suitable for X-ray diffraction analysis were picked up directly from the material (when methanol was used as a solvent, the crystals located on the vessel walls above the solution surface were selected). Identity of the single crystals of (I) grown from EtOH and MeOH was proved by unit cell measurements. Melting point measurements were performed with a Microscopic Melting Point X4 apparatus (Beijing MAISIQI High-Tech Co., Ltd.)

Refinement

All non-H atoms were refined anisotropically. All H-atoms were found from the difference Fourier synthesis and refined isotropically.

Computing details

Data collection: *APEX2* (Bruker, 2007); cell refinement: *SAINT* (Bruker, 2007); data reduction: *SAINT* (Bruker, 2007); program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008) and OLEX2 (Dolomanov *et al.*, 2009); software used to prepare material for publication: *SHELXTL* (Sheldrick, 2008) and OLEX2 (Dolomanov *et al.*, 2009).

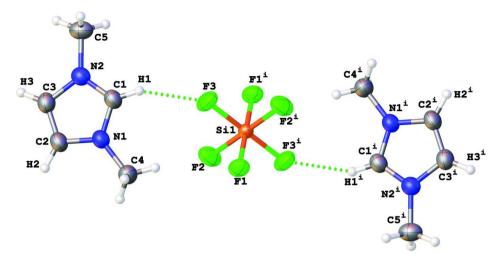


Figure 1 Formula unit of (I) along with atom labelling. Thermal ellipsoids are shown at 50% probability level. Symmetry code: (i) -x + 1, -y + 1, -z + 1. C—H···F contacts are depicted as dotted lines.

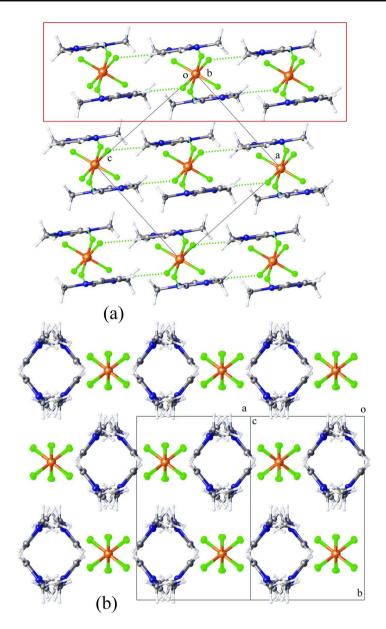


Figure 2 Packing diagrams for (I) [(a), a view along the b-axis] and (Ia) [(b), a view along the (-1, 0, 1) direction]. Ball-and-stick drawings. C—H···F contacts in (I) are depicted as dotted lines and omitted in (Ia) for clarity. One of the layers in the lattice of (I) is framed.

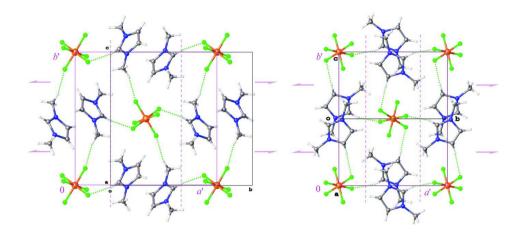


Figure 3

Ball-and-stick drawings of F···H binded layers (layer group $p2_1/b11$) in (Ia; left; a view along a-axis; $N_1 = [D_2^2(4)]_{H1} \cdot D_2^2(4)$, $N_2 = [C_2^2(8)]_{H2,H1}$) and in (I) [right; a view along (1, 0, 1) direction; $N_1 = [D_2^2(4)]_{H4}D_2^2(4)$, $N_2 = [C_2^2(8)]_{H2,H4}$]. The F···H contacts are depicted as dotted lines. Symmetry diagrams for layer group $p2_1/b11$ are also provided in pink colour [a' = 11.988, b' = 11.258 Å for (Ia) and a' = 9.7901 (9), 12.0377 (9) Å for (I); the inversion centres are omitted for clarity]. For description of the graph set notation, see: Etter et al. (1990), Bernstein et al. (1995), Grell et al. (1999).

Bis(1,3-dimethyl-1*H*-imidazolium) hexafluorosilicate

Crystal data

2C₅H₉N²⁺·SiF₆²⁻ F(000) = 348 $M_r = 336.38$ $D_{\rm x} = 1.581 \; {\rm Mg \; m^{-3}}$ Monoclinic, $P2_1/n$ Melting point: 550 K Hall symbol: -P 2yn Mo $K\alpha$ radiation, $\lambda = 0.71073$ Å a = 8.2240 (8) Å Cell parameters from 3479 reflections b = 9.7901 (9) Å $\theta = 2.3 - 28.3^{\circ}$ c = 8.7753 (9) Å $\mu = 0.23 \text{ mm}^{-1}$ $\beta = 90.106 (1)^{\circ}$ T = 296 K $V = 706.53 (12) \text{ Å}^3$ Plate, colourless Z = 2 $0.40 \times 0.39 \times 0.05 \text{ mm}$

Data collection

Bruker SMART APEXII 3670 measured reflections 1373 independent reflections diffractometer Radiation source: fine-focus sealed tube 1228 reflections with $I > 2\sigma(I)$ Graphite monochromator $R_{\rm int} = 0.020$ $\theta_{\text{max}} = 26.0^{\circ}, \ \theta_{\text{min}} = 3.2^{\circ}$ $h = -10 \rightarrow 10$ Detector resolution: 8.333 pixels mm⁻¹ phi and ω scans Absorption correction: multi-scan $k = -12 \rightarrow 9$ (SADABS; Sheldrick, 1996) $l = -10 \rightarrow 8$ $T_{\min} = 0.913, T_{\max} = 0.988$

Refinement

Refinement on F^2 134 parameters Least-squares matrix: full 0 restraints $R[F^2 > 2\sigma(F^2)] = 0.028$ Primary atom site location: structure-invariant direct methods S = 1.09 Secondary atom site location: difference Fourier 1373 reflections Hydrogen site location: difference Fourier map All H-atom parameters refined $w = 1/[\sigma^2(F_o^2) + (0.0471P)^2 + 0.1056P]$ where $P = (F_o^2 + 2F_c^2)/3$ $(\Delta/\sigma)_{\rm max} < 0.001$

 $\Delta \rho_{\text{max}} = 0.18 \text{ e Å}^{-3}$ $\Delta \rho_{\text{min}} = -0.22 \text{ e Å}^{-3}$ Extinction correction: SHELXL, $Fc^* = kFc[1 + 0.001xFc^2\lambda^3/\sin(2\theta)]^{-1/4}$ Extinction coefficient: 0.065 (7)

Special details

Experimental. A very tight closeness of the β -angle to 90° presented a certain difficulty in determination of the actual crystal system and the space group for (I).

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F^2 , conventional R-factors R are based on F, with F set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on F^2 are statistically about twice as large as those based on F, and F-factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\mathring{A}^2)

	X	y	Z	$U_{ m iso}$ */ $U_{ m eq}$	
Si1	0.5000	0.5000	0.5000	0.02918 (18)	
F1	0.31022 (9)	0.53884 (9)	0.55758 (10)	0.0445 (3)	
F2	0.51424 (12)	0.38309 (9)	0.63991 (10)	0.0563 (3)	
F3	0.42533 (10)	0.38065 (9)	0.38175 (11)	0.0532 (3)	
N1	0.22279 (13)	0.08942 (11)	0.52963 (12)	0.0362 (3)	
N2	0.34964 (14)	-0.03111 (12)	0.36255 (13)	0.0373 (3)	
C1	0.31135 (17)	0.09435 (15)	0.40423 (16)	0.0387 (3)	
C2	0.20313 (19)	-0.04525 (15)	0.56970 (17)	0.0419 (3)	
C3	0.28241 (18)	-0.12049 (16)	0.46592 (16)	0.0423 (3)	
C4	0.1593 (2)	0.20729 (16)	0.61283 (19)	0.0462 (4)	
C5	0.4404 (2)	-0.06783 (19)	0.22545 (18)	0.0482 (4)	
H1	0.341 (2)	0.1721 (19)	0.3610 (19)	0.048 (4)*	
H2	0.146(2)	-0.0695 (18)	0.658(2)	0.054 (5)*	
Н3	0.297(2)	-0.2124 (19)	0.4561 (19)	0.050 (5)*	
H4A	0.218(3)	0.282(2)	0.590(2)	0.074 (6)*	
H4B	0.048(3)	0.227(2)	0.580(3)	0.080 (6)*	
H4C	0.162(3)	0.188(2)	0.718(3)	0.093 (7)*	
H5A	0.538 (3)	-0.015 (2)	0.227(3)	0.071 (6)*	
H5B	0.377 (3)	-0.058 (2)	0.141 (3)	0.074 (6)*	
H5C	0.479 (3)	-0.164 (3)	0.229 (3)	0.094 (7)*	

Atomic displacement parameters (\mathring{A}^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
Si1	0.0312 (3)	0.0258 (3)	0.0306(3)	-0.00187 (16)	0.00740 (19)	-0.00332 (17)
F1	0.0342 (4)	0.0494 (5)	0.0499 (5)	0.0012(3)	0.0113 (4)	-0.0102 (4)
F2	0.0701 (6)	0.0494 (5)	0.0494 (5)	0.0135 (4)	0.0180 (4)	0.0160 (4)
F3	0.0480 (5)	0.0516 (5)	0.0599 (6)	-0.0113 (4)	0.0085 (4)	-0.0269 (4)
N1	0.0388 (6)	0.0355 (6)	0.0343 (6)	-0.0044(4)	0.0013 (5)	0.0033 (4)
N2	0.0358 (6)	0.0419 (6)	0.0343 (6)	-0.0026 (5)	-0.0012 (5)	0.0007 (4)

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C1	0.0409 (7)	0.0381 (7)	0.0371 (7)	-0.0041 (6)	0.0022 (6)	0.0054 (6)	
C2	0.0483 (8)	0.0387 (7)	0.0386 (7)	-0.0075 (6)	0.0025 (6)	0.0060(6)	
C3	0.0488 (8)	0.0361 (7)	0.0419 (8)	-0.0048(6)	-0.0018 (6)	0.0034 (6)	
C4	0.0532 (9)	0.0391 (8)	0.0463 (9)	-0.0031 (7)	0.0107 (7)	-0.0017(6)	
C5	0.0454 (8)	0.0607 (10)	0.0384 (8)	0.0026 (7)	0.0036 (6)	-0.0050 (7)	

Geometric parameters (Å, °)

Geometric parameters (A, *)			
Si1—F3 ⁱ	1.6783 (8)	N2—C5	1.4619 (19)
Si1—F3	1.6783 (8)	C1—H1	0.884 (19)
Si1—F2	1.6824 (8)	C2—C3	1.341 (2)
Si1—F2 ⁱ	1.6824 (8)	C2—H2	0.934 (19)
Si1—F1	1.6849 (8)	C3—H3	0.912 (18)
Si1—F1 ⁱ	1.6849 (8)	C4—H4A	0.90 (2)
N1—C1	1.3216 (18)	C4—H4B	0.98 (2)
N1—C2	1.3742 (18)	C4—H4C	0.94(3)
N1—C4	1.4625 (19)	C5—H5A	0.96 (3)
N2—C1	1.3199 (18)	C5—H5B	0.91 (2)
N2—C3	1.3770 (19)	C5—H5C	0.99 (3)
F3 ⁱ —Si1—F3	180.0	N2—C1—N1	109.20 (12)
F3 ⁱ —Si1—F2	89.86 (5)	N2—C1—H1	128.1 (11)
F3—Si1—F2	90.14 (5)	N1—C1—H1	122.7 (11)
F3 ⁱ —Si1—F2 ⁱ	90.14 (5)	C3—C2—N1	107.19 (13)
F3—Si1—F2 ⁱ	89.86 (5)	C3—C2—H2	131.8 (11)
F2—Si1—F2 ⁱ	180.0	N1—C2—H2	121.0 (11)
F3 ⁱ —Si1—F1	89.75 (4)	C2—C3—N2	107.14 (13)
F3—Si1—F1	90.25 (4)	C2—C3—H3	132.2 (11)
F2—Si1—F1	89.88 (4)	N2—C3—H3	120.6 (11)
F2 ⁱ —Si1—F1	90.12 (4)	N1—C4—H4A	109.4 (14)
F3 ⁱ —Si1—F1 ⁱ	90.25 (4)	N1—C4—H4B	110.0 (13)
F3—Si1—F1 ⁱ	89.75 (4)	H4A—C4—H4B	106.4 (18)
F2—Si1—F1 ⁱ	90.12 (4)	N1—C4—H4C	108.6 (15)
F2 ⁱ —Si1—F1 ⁱ	89.88 (4)	H4A—C4—H4C	112 (2)
F1—Si1—F1 ⁱ	180.00 (6)	H4B—C4—H4C	110 (2)
C1—N1—C2	108.26 (12)	N2—C5—H5A	106.3 (14)
C1—N1—C4	125.78 (12)	N2—C5—H5B	110.8 (14)
C2—N1—C4	125.94 (12)	H5A—C5—H5B	115.6 (19)
C1—N2—C3	108.21 (12)	N2—C5—H5C	111.8 (14)
C1—N2—C5	125.41 (13)	H5A—C5—H5C	104.5 (19)
C3—N2—C5	126.31 (13)	H5B—C5—H5C	107.7 (19)
C3—N2—C1—N1	0.05 (16)	C4—N1—C2—C3	-178.71 (14)
C5—N2—C1—N1	177.05 (13)	N1—C2—C3—N2	-0.22 (17)
C2—N1—C1—N2	-0.19 (16)	C1—N2—C3—C2	0.11 (17)
C4—N1—C1—N2	178.78 (13)	C5—N2—C3—C2	-176.85 (14)
C1—N1—C2—C3	0.26 (16)		

Symmetry code: (i) -x+1, -y+1, -z+1.

supplementary materials

Hydrogen-bond geometry (Å, °)

<i>D</i> —H··· <i>A</i>	<i>D</i> —H	$H\cdots A$	D··· A	<i>D</i> —H··· <i>A</i>
C1—H1···F3	0.884 (18)	2.164 (19)	2.9622 (17)	149.8 (14)
C2 ⁱⁱ —H2 ⁱⁱ ···F2	0.934 (19)	2.26 (2)	3.1935 (18)	174.0 (5)

Symmetry code: (ii) -x+1/2, y+1/2, -z+3/2.